# MJ15003 (NPN), MJ15004 (PNP)

# **Complementary Silicon Power Transistors**

The MJ15003 and MJ15004 are power transistors designed for high power audio, disk head positioners and other linear applications.

#### Features

- High Safe Operating Area
- For Low Distortion Complementary Designs
- High DC Current Gain
- These Devices are Pb-Free and are RoHS Compliant\*

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	140	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	140	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	5	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	20	Adc
Base Current – Continuous	Ι <sub>Β</sub>	5	Adc
Emitter Current – Continuous	١ <sub>E</sub>	25	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	250 1.43	W W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +200	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### THERMAL CHARACTERISTICS

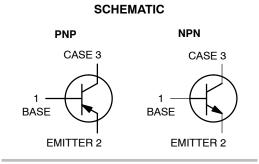
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.70	°C/W
Maximum Lead Temperature for Soldering Purposes $1/16''$ from Case for $\leq 10$ secs	ΤL	265	°C



### **ON Semiconductor®**

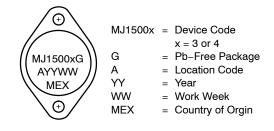
http://onsemi.com

# 20 AMPERE POWER TRANSISTORS COMPLEMENTARY SILICON 140 VOLTS, 250 WATTS





#### MARKING DIAGRAM



#### ORDERING INFORMATION

Device	Package	Shipping
MJ15003G	TO-204AA (Pb-Free)	100 Units/Tray
MJ15004G	TO-204AA (Pb-Free)	100 Units/Tray

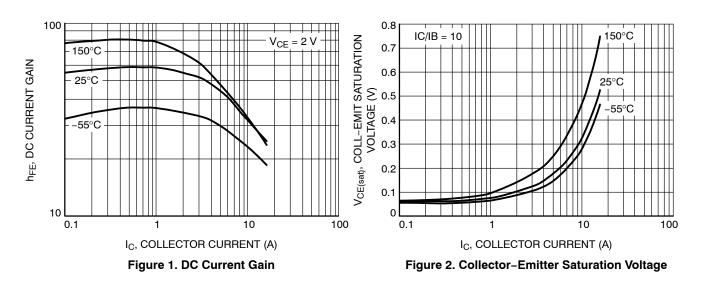
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## MJ15003 (NPN), MJ15004 (PNP)

#### **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector Emitter Sustaining Voltage (Note 1) $(I_{C} = 200 \text{ mAdc}, I_{B} = 0)$	V <sub>CEO(sus)</sub>	140	-	Vdc
$      Collector Cutoff Current \\ (V_{CE} = 140 Vdc, V_{BE(off)} = 1.5 Vdc) \\ (V_{CE} = 140 Vdc, V_{BE(off)} = 1.5 Vdc, T_C = 150^{\circ}C) $	ICEX		100 2	μAdc mAdc
Collector Cutoff Current ( $V_{CE} = 140$ Vdc, $I_B = 0$ )	I <sub>CEO</sub>	-	250	μAdc
Emitter Cutoff Current ( $V_{EB} = 5 \text{ Vdc}, I_C = 0$ )	I <sub>EBO</sub>	-	100	μAdc
SECOND BREAKDOWN		•		
Second Breakdown Collector Current with Base Forward Biased $(V_{CE} = 50 \text{ Vdc}, t = 1 \text{ s (non repetitive)})$ $(V_{CE} = 100 \text{ Vdc}, t = 1 \text{ s (non repetitive)})$	I <sub>S/b</sub>	5.0 1.0		Adc
ON CHARACTERISTICS	·			
DC Current Gain (I <sub>C</sub> = 5 Adc, V <sub>CE</sub> = 2 Vdc)	h <sub>FE</sub>	25	150	-
Collector Emitter Saturation Voltage $(I_C = 5 \text{ Adc}, I_B = 0.5 \text{ Adc})$	V <sub>CE(sat)</sub>	-	1.0	Vdc
Base Emitter On Voltage (I <sub>C</sub> = 5 Adc, V <sub>CE</sub> = 2 Vdc)	V <sub>BE(on)</sub>	-	2.0	Vdc
DYNAMIC CHARACTERISTICS		•	•	
Current Gain — Bandwidth Product ( $I_C = 0.5$ Adc, $V_{CE} = 10$ Vdc, $f_{test} = 0.5$ MHz)	f <sub>T</sub>	2.0	-	MHz
Output Capacitance $(V_{CB} = 10 \text{ Vdc}, I_E = 0, f_{test} = 1 \text{ MHz})$	c <sub>ob</sub>	_	1000	pF
Dulea Test: Dulea Width - 300 us. Duty Cycla < 2%	•			

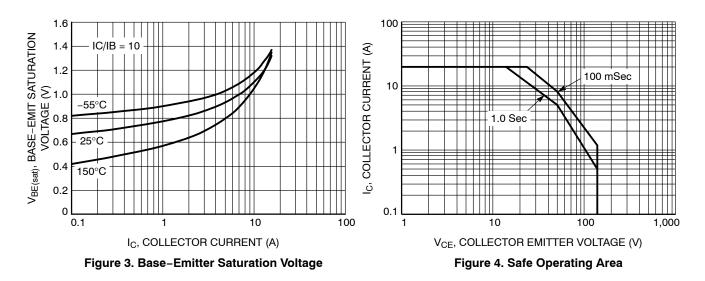
1. Pulse Test: Pulse Width = 300  $\mu s,$  Duty Cycle  $\leq$  2%.



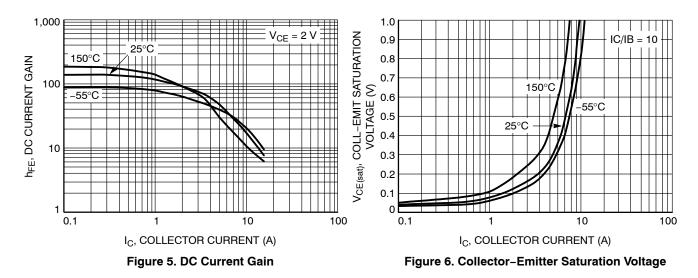
## **TYPICAL CHARACTERISTICS MJ15003G (NPN)**

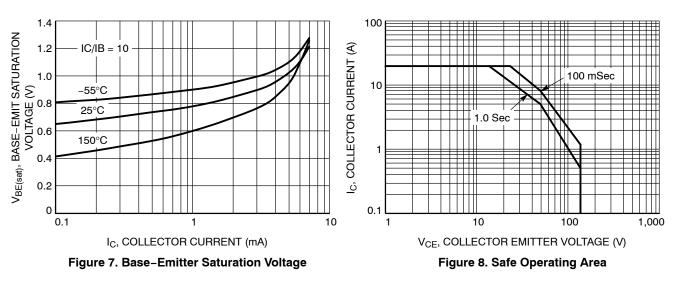
### MJ15003 (NPN), MJ15004 (PNP)

#### **TYPICAL CHARACTERISTICS MJ15003G (NPN)**









#### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



DIMENSIONS			
SCALE 1:1	TO–204 (TO–3) CASE 1–07 ISSUE Z	)	DATE 05/18/1988
$ \begin{array}{c}                                     $	$ \begin{array}{c}                                     $	NOTES: 1. DIMENSIONING AND TC Y14.5M, 1982. 2. CONTROLLING DIMENS 3. ALL RULES AND NOTES REFERENCED TO-204A MIN MAX A 1.550 REF B 1.050 C 0.250 0.335 D 0.038 0.043 E 0.055 0.070 G 0.430 BSC H 0.215 BSC K 0.440 0.480 L 0.665 BSC N 0.830 Q 0.151 0.165 U 1.187 BSC V 0.131 0.188	ION: INCH.
STYLE 1: PIN 1. BASE 2. EMITTER CASE: COLLECTOR STYLE 6: PIN 1. GATE 2. EMITTER CASE: COLLECTOR	STYLE 2:         STYLE 3:           PIN 1. BASE         PIN 1. GATE           2. COLLECTOR         2. SOURCE           CASE: EMITTER         CASE: DRAIN           STYLE 7:         STYLE 8:           PIN 1. ANODE         PIN 1. CATHODE #1           2. OPEN         2. CATHODE #2           CASE: CATHODE         CASE: ANODE	STYLE 4: STYLE 5: PIN 1. GROUND 2. INPUT CASE: OUTPUT STYLE 9: PIN 1. ANODE #1 2. ANODE #2 CASE: CATHODE	E AL TRIP/DELAY

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